

IRFZ44N MOSFET IC DIP

Slug: irlz44n-mosfet-ic-dip-3-package



TECHNICAL SPECIFICATIONS & SUMMARY

[Mosfet] IRFZ44N Power MOSFETIRFZ44N is an advanced HEXFET Power MOSFETs that utilizes advanced processing techniques to achieve extremely low on-resistance per silicon area. This benefit, combined with the fast switching speed and ruggedized device design that exFAT power MOSFETs are well known for, provides the designer with an extremely efficient and reliable device for use in a wide variety of applications. The TO-220 package is universally preferred for all commercial-industrial applications at power dissipation levels to approximately 50 watts. The low thermal resistance and low package cost of the TO-220 contribute to its wide acceptance throughout the industry. Specification: Application: Electronic Continuous Drain Current: 49A Power Dissipation: 94W Pulsed Drain Current: 160A Features: Advanced Process Technology Ultra-Low On-Resistance Dynamic DV/DT Rating 175 DegreeC Operating Temperature Fast Switching Fully Avalanche Rated Datasheet: Download Package Content: 1 x IRFZ44N Mosfet

UNIT PRICE (EX. GST)

Rs. 29

WITH 18% GST

Rs. 34

In stock: 0 units - HSN: 85044090
Order online at uniksystem.in for bulk pricing.